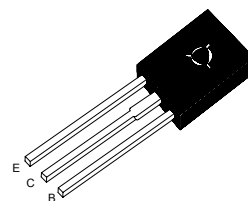


ST 2SB772T

PNP Silicon Epitaxial Power Transistor

These devices are intended for use in audio frequency power amplifier and low speed switching applications



TO-126 Plastic Package

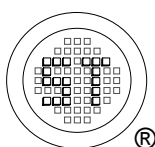
Absolute Maximum Ratings ($T_a = 25\text{ }^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Collector Base Voltage	$-V_{CBO}$	40	V
Collector Emitter Voltage	$-V_{CEO}$	30	V
Emitter Base Voltage	$-V_{EBO}$	5	V
Collector Current - DC	$-I_C$	3	A
Collector Current - Pulse ¹⁾	$-I_{CP}$	7	A
Base Current - DC	$-I_B$	0.6	A
Total Power Dissipation	P_{tot}	10 1	W
Operating and Storage Junction Temperature Range	T_j, T_{stg}	- 65 to + 150	$^\circ\text{C}$

¹⁾ PW = 10 ms, Duty Cycle \leq 50 %

Characteristics at $T_a = 25\text{ }^\circ\text{C}$

Parameter	Symbol	Min.	Typ.	Max.	Unit	
DC Current Gain at $-V_{CE} = 2\text{ V}$, $-I_C = 20\text{ mA}$ at $-V_{CE} = 2\text{ V}$, $-I_C = 1\text{ A}$ Current Gain Group	R	30	-	-	-	
	Q	60	-	120	-	
	P	100	-	200	-	
		h _{FE}	160	-	320	-
	E	h _{FE}	200	-	400	-
Collector Base Cutoff Current at $-V_{CB} = 30\text{ V}$	$-I_{CBO}$	-	-	1	μA	
Emitter Base Cutoff Current at $-V_{EB} = 3\text{ V}$	$-I_{EBO}$	-	-	1	μA	
Collector Base Breakdown Voltage at $-I_C = 1\text{ mA}$	$-V_{(BR)CBO}$	40	-	-	V	
Collector Emitter Breakdown Voltage at $-I_C = 1\text{ mA}$	$-V_{(BR)CEO}$	30	-	-	V	
Emitter Base Breakdown Voltage at $-I_E = 1\text{ mA}$	$-V_{(BR)EBO}$	5	-	-	V	
Collector Emitter Saturation Voltage at $-I_C = 2\text{ A}$, $-I_B = 200\text{ mA}$	$-V_{CE(sat)}$	-	-	0.5	V	
Base Emitter Saturation Voltage at $-I_C = 2\text{ A}$, $-I_B = 200\text{ mA}$	$-V_{BE(sat)}$	-	-	2	V	
Emitter Output Capacitance at $-V_{CB} = 10\text{ V}$, $f = 1\text{ MHz}$	C_{ob}	-	55	-	pF	
Current Gain Bandwidth Product at $-I_C = 100\text{ mA}$, $-V_{CE} = 5\text{ V}$	f_T	-	80	-	MHz	



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Dated : 24/08/2010 Rev:01

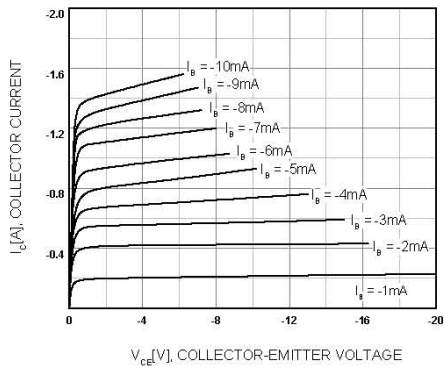


Figure 1. Static Characteristic

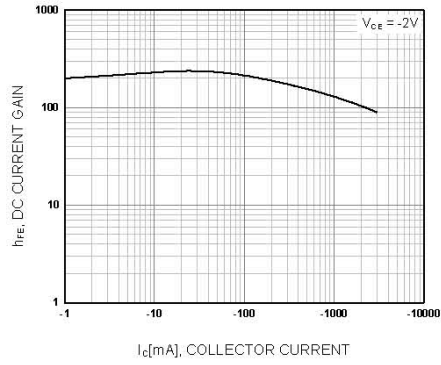


Figure 2. DC current Gain

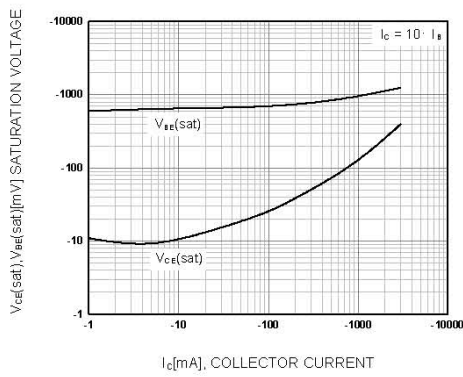


Figure 3. Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage

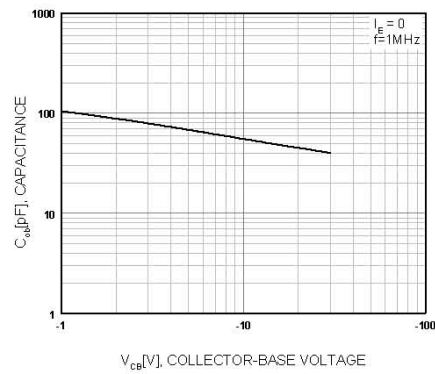


Figure 4. Collector Output Capacitance

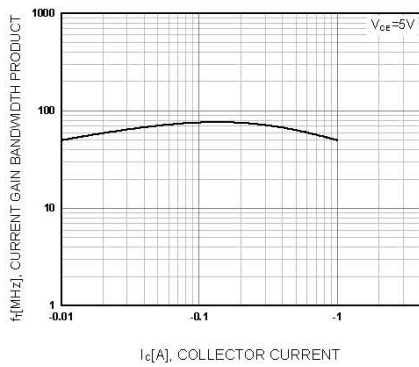


Figure 5. Current Gain Bandwidth Product

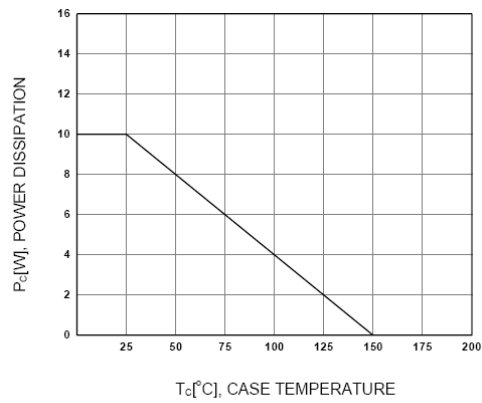


Figure 6 Power Derating

